NSN 5962-01-347-7476

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View Online at https://aerobasegroup.com/nsn/5962-01-347-7476

Overall Length:	
1.290 inches	

Overall Height:

0.425 inches

Body Length:

1.290 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

Between 0.150 inches and 0.210 inches

Maximum Power Dissipation Rating:

1.04 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and burn in and 3-state output and programmable and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-3 mil-m-38510

Current Rating Per Characteristic:

190.00 milliamperes supply

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

55.00 nanoseconds access

Memory Device Type:

Prom

Special Features:

Nuclear hardness critical item

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Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0